IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

	Application Filing Date	Serial	No.																 . J	uly	09/90 13.	5,288 2001
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Attorney's Docket No																						

RESPONSE TO DECEMBER 19, 2001 OFFICE ACTION

To:

Box Non-Fee Amendment

Assistant Commissioner for Patents

Washington, D.C. 20231

VIA U. S. EXPRESS MAIL

From:

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Responsive to the Office Action dated December 19, 2001, Applicant amends and remarks as follows: THE CHILL

AMENDMENTS

In the Specification

Please replace the paragraph beginning at line 8 on page 9 with the following clean replacement paragraph in accordance with 37 CFR § 1.121(b)(1)(ii). A marked-up version showing amendments to the specification paragraph being changed is provided in one or more accompanying pages separate from this amendment in accordance with 37 CFR § 1.121(b)(1)(iii).

Additional and/or alternate preferred processing can occur in accordance with any of our co-pending U.S. Patent Application Serial No. 09/476,516, filed on January 3, 2000, entitled "Chemical Vapor Deposition Methods Of Forming A High K Dielectric Layer And Methods Of Forming A Capacitor", listing Cem Basceri inventor: U.S. Patent Application Serial No. 09/580,733, filed on May 26, 2000, entitled "Chemical Vapor Deposition Methods And Physical Vapor Deposition Methods", listing Cem Basceri as inventor: and U.S. Patent Application No. 09/905,320, filed concurrently herewith, entitled "Chemical Vapor Deposition Methods Of Forming Barium Strontium Titanate Comprising Dielectric Layers, Including Such Layers Having A Varied Concentration Of Barium And Strontium Within The Layer", listing Cem Basceri and Nancy Alzola as inventors. of these is hereby fully incorporated by reference.